Direct e-beam lithography of PDMS

How to cite:

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Version: Accepted Manuscript

Link(s) to article on publisher’s website:
http://dx.doi.org/doi:10.1016/j.mee.2012.02.049

oro.open.ac.uk
Graphical abstract

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Highlights

► We have shown that there are four distinct regimes in the e-beam exposure of PDMS. ► The phase, elastic modulus and resultant thickness are highly dependent on dose. ► In the solid region, the elastic modulus is tuneable by three orders of magnitude.
Direct e-beam lithography of PDMS

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ARTICLE INFO

Article history:
Available online xxxx

Keywords: e-Beam Lithography PDMS Poly(dimethylsiloxane)

1. Introduction

Poly(dimethylsiloxane) (PDMS) is a versatile material frequently used in the fabrication of micro- and nanoscale devices. It has a unique combination of properties including excellent thermal and chemical stability and non-toxicity making it an attractive material for use in many fields of science, especially in biomedical research [1]. PDMS has a very low glass transition temperature and exists at room temperature in the liquid phase, as a polymer melt. This liquid can be converted into a solid elastomer by cross-linking, a process which is most frequently performed by combining the PDMS with curing agents or catalysts [2]. Generally, the PDMS elastomer is patterned using soft lithography whereby the liquid mixture is poured over a master having relief structure, cured and peeled off [3]. The production of a master and then the PDMS structure is a complicated multi-step process, one that can be greatly simplified by omitting the need of a master by directly patterning the PDMS itself. The most common process for patterning polymers in microengineering is photolithography. PDMS is not photo-sensitive but can be made to be by adding a photoinitiator to the liquid prepolymer [4], although it was found that this method suffers from having relatively low resolution. It has been previously demonstrated that the cross-linking density and mechanical properties of PDMS can be modified by electron beam irradiation [5] and even proton beam bombardment [6]. Its sensitivity to electron radiation [7] has lead to its use as a resist for subsequent substrate patterning [8] albeit generally in a modified form. These modifications have included replacing the methyl groups with phenyl groups to increase the glass transition temperature [9], the addition of an acid generator during exposure and baking to form silicate glass [10] and the use of a pre-curing agent to solidify the PDMS prior to exposure [11].

e-beam lithography (EBL) is a lithographic technique that is widely used to define nanoscale features and while it is a serial method, the ease of design and resolution [12] means it has great potential in being used to generate a great variety of PDMS-based structures. The chemical composition of PDMS is shown in Fig. 1. During e-beam irradiation, it is hypothesized that methyl groups are removed allowing the backbones of different polymer chains to become cross-linked. However, at large doses, the electrons also cause chain scission and the formation of other chemical species. Here we introduce the use of EBL as a viable method of directly patterning liquid PDMS to form permanent surface topographies and micro-scale components. To achieve this goal we analyzed the effects of exposing thin liquid films of PDMS to electron radiation in the dose range 10–50,000 μC/cm² on the resulting elastic modulus and topography. The data shows that PDMS processed using this method is a viable structural material capable of being utilized in the next generation of microfluidic and other micro devices.

2. Fabrication

PDMS with a zero shear viscosity of 1 Pa s was decanted onto clean Si wafers (IDB Technologies, UK; 2 nm native SiO₂ layer)

Please cite this article in press as: J. Bowen et al., Microelectron. Eng. (2012), http://dx.doi.org/10.1016/j.mee.2012.02.049

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and spun at a frequency of 33.3 Hz for 100 min, using a spin processor (WS-400E-6NPP-Lite, Laurell Technologies, USA). The resultant PDMS film thicknesses were in the range 1.1 ± 50 nm and measured using an ellipsometer (UVISEL, Horiba Scientific, UK) operating over the wavelength range 250–800 nm. E-beam exposure was carried out using an FEI XL30 SFEG field emission scanning electron microscope (SEM) equipped with a pattern generator for lithography (Raith Elphy Plus). Arrays of 25 squares of 50 µm were exposed on the sample at a beam energy of 30 keV and beam current 1.02 nA, using the Raith pattern generator. After exposure, the sample was dipped in toluene for 10 s to remove the unexposed areas of the PDMS from the substrate. Visualization of the resultant surface topography (see Fig. 2) was performed using a MicroXAM2 interferometer (Omniscan, UK). It should be noted that the rectangular shape of the first two or three areas in Fig. 2A and B are due to stage drift after repositioning. Care has been taken to ensure this has not affected subsequent data.

3. Experimental analysis of topography and elastic modulus

Acquisition of topographical and mechanical data were performed using a NanoWizard II AFM (JPK, UK) operating in force scan mapping mode, at a temperature of 18 °C and a relative humidity in the range 25–35%. This involved the use of a scanner with a maximum lateral range of 100 × 100 µm and a maximum vertical range of 90 µm in conjunction with a CellHesion module (JPK, UK). Data acquisition was performed using rectangular 130 µm length Si cantilevers (type NSC36/No. Al, Mikro Masch, Estonia) having pyramidal tips with 10 nm nominal radii of curvature. Cantilever spring constants were on the order 0.2 N/m and were calibrated according to the method reported by Bowen et al. [13]. Mechanical data were acquired at 400 surface locations within the 100 × 100 µm scan area by driving the fixed end of the cantilever at a velocity of 20 µm/s towards the sample surface, whilst monitoring the deflection of the free end of the cantilever using a laser beam. Using JPK Data Processing software, a Hertzian model was fitted to data from four separated positions along the center of each exposed square to assess the mechanical response. A maximum compressive load of 5 nN was applied to the surface during data acquisition, which corresponded to a small indentation strain. Topological data, as exemplified in Fig. 3, was obtained via contact mode AFM imaging, employing a compressive load of...
5 nN during scanning. The results were used to measure the thickness of the PDMS remaining after development.

The data in Fig. 4 shows four distinct regimes corresponding to changes in the phase of the PDMS due to increasing exposure dose. At doses below c.a. 30 μC/cm² the PDMS is largely removed during development in toluene as denoted by the reduced thickness. The variability in the Young’s modulus at these low doses suggests that the remaining film consists largely of a residual aggregate of partially cross-linked polymer chains through which the indentation is affected by the proximity of the substrate. Between 30 μC/cm² and 150 μC/cm², the exposed PDMS film appears to be still mostly liquid-like with the apparent increase in elastic modulus most likely corresponding to a change in the viscoelastic properties of the material. It is apparent that cross-linking density is increasing with dose throughout this regime as the amount of PDMS that remains undissolved during development is also increasing. The discontinuity at c.a. 150 μC/cm² in the Young’s modulus data implies a critical cross-linking density at which solidification occurs. At doses above this critical value of 150 μC/cm², the resultant thickness plateaus to a value close to that of the original liquid film. At doses above c.a. 3000 μC/cm², there is an increase in the variability in Young’s modulus and a steady increase in film thickness above that of the original liquid film thickness. This corresponds to the reduction in resolution as seen in Fig. 2 at higher doses. It is likely that the lateral broadening (i.e. the rounding) of the features, see Fig. 3, is due to backscattering, a well established phenomenon.

The vertical swelling is more likely to be due to high dose enhanced solvent penetration as discussed in [14]. This solvent penetration, which is unlikely to be homogenous over the surface of any particular area, will also cause the variation in the Young’s modulus.

4. Conclusions

In this paper the viability of using e-beam lithography to form permanent micro-scale components from thin films of liquid PDMS was investigated. By exposing the PDMS film to a range of doses, it was found that the structure of the resultant film has four distinct phases manifest in both the Young’s modulus and remaining thickness after development. In the solid phase it was shown that the Young’s modulus can be varied over approximately seven orders of magnitude from that of a viscoelastic material through a rubbery regime to that of a glassy one by controlling the electron dose. At higher doses, excessive backscattering was observed as well as swelling, possibly caused by chain scission resulting in poor spatial resolution.

Acknowledgments

The Atomic Force Microscope used in this research were obtained, through Birmingham Science City: Innovative Uses for Advanced Materials in the Modern World (West Midlands Centre for Advanced Materials Project 1 and 2), with support from Advantage.
West Midlands (AWM) and part funded by the European Regional Development Fund (ERDF).

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Please cite this article in press as: J. Bowen et al., Microelectron. Eng. (2012), http://dx.doi.org/10.1016/j.mee.2012.02.049